

# isc N-Channel MOSFET Transistor

# 2SK3131

## **FEATURES**

- Drain Current : I<sub>D</sub>= 50A@ T<sub>C</sub>=25 ℃
- Drain Source Voltage
  - : V<sub>DSS</sub>= 500V(Min)
- Static Drain-Source On-Resistance
  - :  $R_{DS(on)} = 0.11 \Omega (Max) @VGS = 10V$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### **DESCRIPTION**

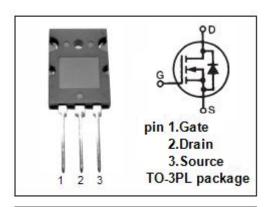
 motor drive, DC-DC converter, power switch and solenoid drive.

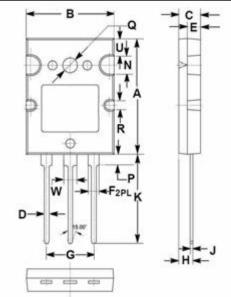
## ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	500	V
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±30	V
I <sub>D</sub>	Drain Current-Continuous	50	А
I <sub>DM</sub>	Drain Current-Single Pluse	200	А
P <sub>D</sub>	Total Dissipation @Tc=25℃	250	W
TJ	Max. Operating Junction Temperature -55~150		$^{\circ}$
T <sub>stg</sub>	Storage Temperature -55~150		$^{\circ}$

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.5	°C/W





	mm		
DIM	MIN	MAX	
Α	25.50	26.50	
В	19.80	20.20	
C	4.50	5.50	
D	0.90	1.10	
E	2.80	3.20	
F	2.40	2.60	
G	10.80	11.00	
Н	3.10	3.30	
J	0.50	0.70	
K	20.00	21.00	
N	3.90	4.50	
Р	2.40	2.60	
Q	3.10	3.50	
R	1.90	2.60	
U	3.90	4.10	
W	2.90	3.25	

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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 10mA	500		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> = 1mA	2.4	3.4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 25A		0.11	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±25V;V <sub>DS</sub> = 0		±10	uA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 500V; V <sub>GS</sub> = 0		0.1	mA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 25A; V <sub>GS</sub> = 0	-	1.7	V



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